NSN 5962-01-538-6106

Memory Microcircuit - Page 1 of 1



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Features Provided:
Electrostatic sensitive and programmed and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
25 input
Terminal Surface Treatment:
Solder
Memory Device Type:
Ram
Memory Capacity:
8kx9
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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